

## **BUW1015**

# HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

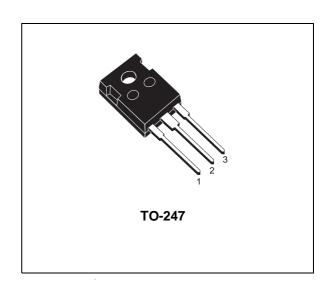
- STMicroelectronics PREFERRED SALESTYPE
- HIGH VOLTAGE CAPABILITY (> 1500 V)
- VERY HIGH SWITCHING SPEED

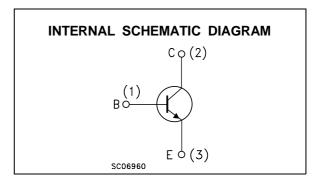
#### **APPLICATIONS:**

 HORIZONTAL DEFLECTION FOR HIGH-END COLOUR TV AND 19" MONITORS

#### **DESCRIPTION**

The BUW1015 is manufactured using Multiepitaxial Mesa technology for cost-effective high performance and uses a Hollow Emitter structure to enhance switching speeds.





#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage (I <sub>E</sub> = 0)	1500	V
$V_{CEO}$	Collector-Emitter Voltage (I <sub>B</sub> = 0)	700	V
$V_{EBO}$	Emitter-Base Voltage (I <sub>C</sub> = 0)	10	V
Ic	Collector Current	14	Α
I <sub>CM</sub>	Collector Peak Current (t <sub>p</sub> < 5 ms)	18	Α
I <sub>B</sub>	Base Current	8	Α
I <sub>BM</sub>	Base Peak Current (t <sub>p</sub> < 5 ms)	11	Α
P <sub>tot</sub>	Total Dissipation at T <sub>c</sub> = 25 °C	160	W
T <sub>stg</sub>	Storage Temperature	-65 to 150	°C
Tj	Max. Operating Junction Temperature	150	°C

February 2002

#### THERMAL DATA

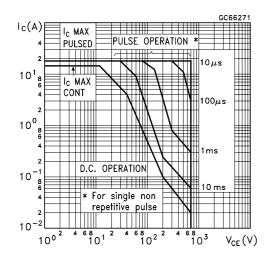
R <sub>thj-case</sub>	Thermal Resistance Junction-case	Max	0.78	°C/W	
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# **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub> = 25 °C unless otherwise specified)

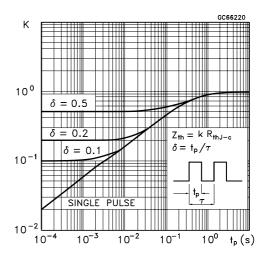
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>CES</sub>	Collector Cut-off Current (V <sub>BE</sub> = 0)	V <sub>CE</sub> = 1500 V V <sub>CE</sub> = 1500 V T <sub>j</sub> = 125 °C			0.2 2	mA mA
I <sub>EBO</sub>	Emitter Cut-off Current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 5 V			100	μΑ
V <sub>CEO(sus)</sub> *	Collector-Emitter Sustaining Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 100 mA	700			>
V <sub>EBO</sub>	Emitter-Base Voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 10 mA	10			V
V <sub>CE(sat)</sub> *	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 10 A I <sub>B</sub> = 2 A			1.5	V
V <sub>BE(sat)</sub> *	Base-Emitter Saturation Voltage	I <sub>C</sub> = 10 A I <sub>B</sub> = 2 A			1.5	V
h <sub>FE</sub> *	DC Current Gain	$I_{C} = 10 \text{ A}$ $V_{CE} = 5 \text{ V}$ $I_{C} = 10 \text{ A}$ $V_{CE} = 5 \text{ V}$ $T_{j} = 100 ^{\circ}\text{C}$	7 5	10	14	
t <sub>s</sub>	RESISTIVE LOAD Storage Time Fall Time	$V_{CC} = 400 \text{ V}$ $I_{C} = 10 \text{ A}$ $I_{B1} = 2 \text{ A}$ $I_{B2} = -6 \text{ A}$		1.5 110		μs ns
t <sub>s</sub> t <sub>f</sub>	INDUCTIVE LOAD Storage Time Fall Time	$\begin{aligned} I_{C} &= 10 \text{ A} & f &= 31250 \text{ Hz} \\ I_{B1} &= 2 \text{ A} & I_{B2} &= -6 \text{ A} \\ V_{ceflyback} &= 1200 \sin \left(\frac{\pi}{5} \cdot 10^{6}\right) t \text{ V} \end{aligned}$		4 220		μs ns
t <sub>s</sub>	INDUCTIVE LOAD Storage Time Fall Time	$I_{C} = 6 \text{ A} \qquad f = 64 \text{ KHz}$ $I_{B1} = 1 \text{ A}$ $V_{beoff} = -2 \text{ V}$ $V_{ceflyback} = 1100 \sin\left(\frac{\pi}{5} \cdot 10^{6}\right) t \text{ V}$		3.7 200		μs ns

<sup>\*</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

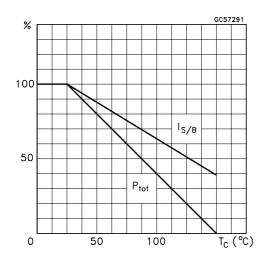
#### Safe Operating Area



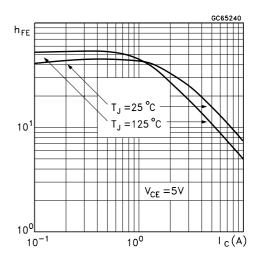
#### Thermal Impedance



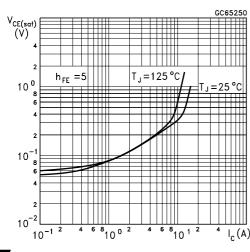
#### **Derating Curve**



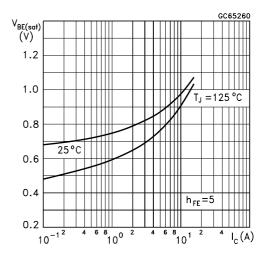
DC Current Gain



#### Collector Emitter Saturation Voltage

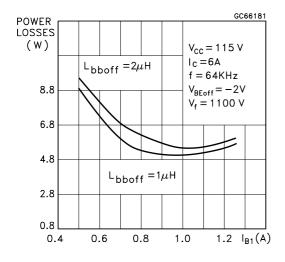


Base Emitter Saturation Voltage

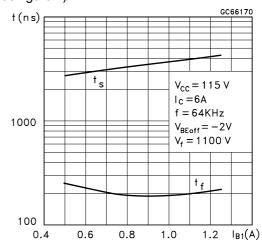


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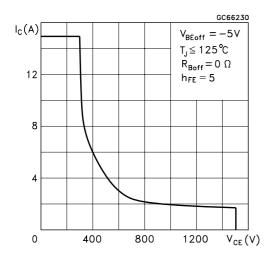
#### Power Losses at 64 KHz



# Switching Time Inductive Load at 64KHz (see figure 2)



#### Reverse Biased SOA



#### **BASE DRIVE INFORMATION**

In order to saturate the power switch and reduce conduction losses, adequate direct base current I<sub>B1</sub> has to be provided for the lowest gain h<sub>FE</sub> at T<sub>i</sub> = 100 °C (line scan phase). On the other hand, negative base current IB2 must be provided the transistor to turn off (retrace phase). Most of the dissipation, especially in the application, occurs at switch-off so it is essential to determine the value of IB2 which minimizes power losses, fall time tf and, consequently, Ti. A new set of curves have been defined to give total power losses, ts and tf as a function of IB1 at 64 KHz scanning frequencies for choosing the

optimum drive. The test circuit is illustrated in figure 1.

The values of L and C are calculated from the following equations:

$$\frac{1}{2}L(I_C)^2 = \frac{1}{2}C(V_{CEfly})^2$$
$$\omega = 2\pi f = \frac{1}{\sqrt{LC}}$$

Where I<sub>C</sub>= operating collector current, V<sub>CEfly</sub>= flyback voltage, f= frequency of oscillation during retrace.

Figure 1: Inductive Load Switching Test Circuit.

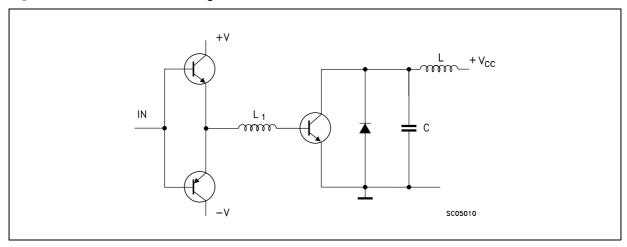
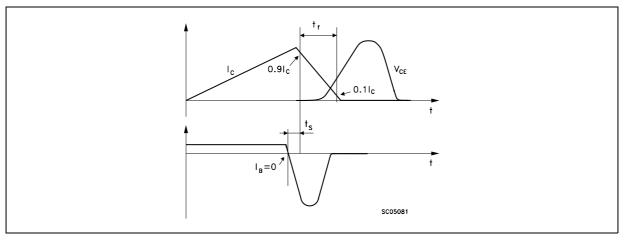
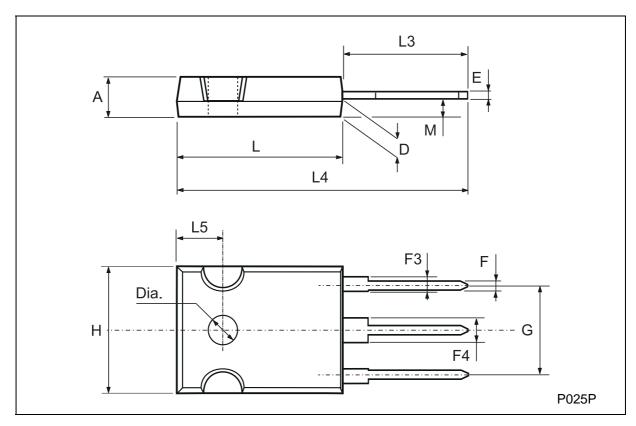


Figure 2: Switching Waveforms in a Deflection Circuit



### **TO-247 MECHANICAL DATA**

DIM.	mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	4.7		5.3	0.185		0.209
D	2.2		2.6	0.087		0.102
Е	0.4		0.8	0.016		0.031
F	1		1.4	0.039		0.055
F3	2		2.4	0.079		0.094
F4	3		3.4	0.118		0.134
G		10.9			0.429	
Н	15.3		15.9	0.602		0.626
L	19.7		20.3	0.776		0.779
L3	14.2		14.8	0.559		0.582
L4		34.6			1.362	
L5		5.5			0.217	
М	2		3	0.079		0.118



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